SCBS008C - APRIL 1987 - REVISED NOVEMBER 1993

- State-of-the-Art BiCMOS Design Significantly Reduces I<sub>CCZ</sub>
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- P-N-P Inputs Reduce DC Loading
- Flow-Through Architecture Optimizes
  PCB Layout
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (JT, NT)

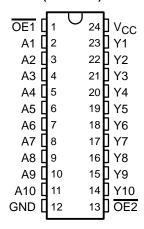
## description

These 10-bit buffers and bus drivers provide high-performance bus interface for wide data paths or buses carrying parity.

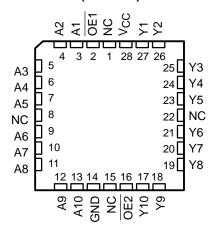
The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all ten outputs are in the high-impedance state. The outputs are also in the high-impedance state during power-up and power-down conditions. The outputs remain in the high-impedance state while the device is powered down.

The SN54BCT29827B is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74BCT29827B is characterized for operation from 0°C to 70°C.

### SN54BCT29827B ... JT OR W PACKAGE SN74BCT29827B ... DW OR NT PACKAGE (TOP VIEW)



# SN54BCT29827B . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

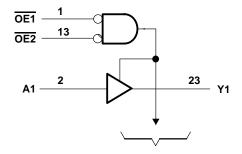
#### **FUNCTION TABLE**

	INPUTS	OUTPUT	
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
Χ	Н	Χ	z

# logic symbol†

#### ΕN 13 OE2 23 **Y1** Α1 22 A2 **Y2** 4 21 **Y3 A3** 5 20 Α4 **Y4** 19 Α5 **Y5** 7 18 **Y6** A6 8 17 **A7 Y7** 16 **Y8 A8** 10 15 Α9 Υ9 11 14 Y10 A10

# logic diagram (positive logic)



To Nine Other Channels

Pin numbers shown are for the DW, JT, NT, and W packages.

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the disabled or power-off state, V <sub>O</sub>	0.5 V to 5.5 V
Voltage range applied to any output in the high state, V <sub>O</sub>	–0.5 V to V <sub>CC</sub>
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–30 mA
Current into any output in the low state, IO: SN54BCT29827B	48 mA
SN74BCT29827B	96 mA
Operating free-air temperature range: SN54BCT29827B	–55°C to 125°C
SN74BCT29827B	0°C to 70°C
Storage temperature range	–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## recommended operating conditions

		SN54BCT29827B			SN74BCT29827B			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V <sub>IL</sub>	Low-level input voltage			0.8			0.8	V
lıĸ	Input clamp current			-18			-18	mA
ІОН	High-level output current			-15			-24	mA
l <sub>OL</sub>	Low-level output current			24			48	mA
TA	Operating free-air temperature	-55		125	0		70	°C



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			SN54BCT29827B			SN74BCT29827B			
PARAMETER				TYP	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK	$V_{CC} = 4.5 \text{ V},$	I <sub>I</sub> = −18 mA			-1.2			-1.2	V	
	V <sub>CC</sub> = 4.5 V	$I_{OH} = -15 \text{ mA}$	2	3.2		2.4	3.3			
Voн		$I_{OH} = -24 \text{ mA}$				2	3.1		V	
	$V_{CC} = 4.75 \text{ V},$	$I_{OH} = -3 \text{ mA}$				2.7				
Vo	V 45V	$I_{OL} = 24 \text{ mA}$		0.38	0.55				V	
VOL	V <sub>CC</sub> = 4.5 V	$I_{OL} = 48 \text{ mA}$					0.42	0.5		
lı	$V_{CC} = 5.5 \text{ V},$	$V_I = 7 V$			0.1			0.1	mA	
lн	$V_{CC} = 5.5 \text{ V},$	$V_{I} = 2.7 \text{ V}$			20			20	μΑ	
I <sub>IL</sub>	$V_{CC} = 5.5 \text{ V},$	V <sub>I</sub> = 0.5 V			-0.2			-0.2	mA	
los <sup>‡</sup>	$V_{CC} = 5.5 \text{ V},$	V <sub>O</sub> = 0	-75		-250	-75		-250	mA	
lozh	$V_{CC} = 5.5 \text{ V},$	$V_0 = 2.7 \text{ V}$			20			20	μΑ	
lozL	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.5 V			-20			-20	μΑ	
ICCL	V <sub>CC</sub> = 5.5 V,	Outputs open		28			28	40	mA	
Іссн	V <sub>CC</sub> = 5.5 V,	Outputs open		15			15	25	mA	
Iccz	$V_{CC} = 5.5 \text{ V},$	Outputs open		3.5			3.5	6	mA	
C <sub>i</sub>	$V_{CC} = 5 V$ ,	$V_{I} = 2.5 \text{ V or } 0.5 \text{ V}$		6			6		pF	
Co	V <sub>CC</sub> = 5 V,	$V_0 = 2.5 \text{ V or } 0.5 \text{ V}$		8			8		pF	

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L$ = 50 pF (unless otherwise noted) (see Note 2)

PARAMETER	FROM (INPUT) (	TO (OUTPUT)	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C		SN54BCT29827B		SN74BCT29827B		UNIT		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
<sup>t</sup> PLH	А	A Y	1.6	3.3	5.3	1.6	5.5	1.6	5.5	ns	
<sup>t</sup> PHL			2.7	5.1	7.3	2.7	7.7	2.7	7.5	115	
<sup>t</sup> PZH	ŌĒ	<del></del>	<b>&gt;</b>	2.7	5.3	7.9	2.7	10.6	2.7	9.1	
t <sub>PZL</sub>		· · · · · · · · · · · · · · · · · · ·	5.3	8.5	12.1	5.3	13.5	5.3	12.8	ns	
<sup>t</sup> PHZ	ŌĒ	OF.	V	2.8	5.4	8.2	2.8	9.4	2.8	8.8	
t <sub>PLZ</sub>		T	2.3	5.1	7.6	2.3	9.1	2.3	8.4	ns	

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

<sup>‡</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

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